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April 1st, 2010 Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (http://www.renesas.com)

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M61503FP

Tone Control/Volume Control

REJ03F0214-0201 Rev.2.01 Mar 31, 2008

Description

The M61503FP is a sound controller IC with the "BBE sound" sound technology.

It can realize articulation of reconstruction sound by BBE surround built-in reproduce tone more naturally.

Note: This device is producted under license from BBE sound Lab, Inc.(USA) and available to only licenses.

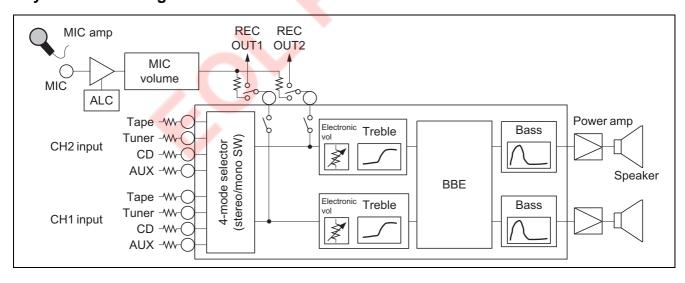
Features

- Built-in "BBE sound" sound technology
- Electronic volume. 0 to -84 dB, the infinitesimal.
- 2-band tone control
 Bass (0 to +21 dB/3 dB STEP)
 Treble (0 to +9 dB/3 dB STEP)

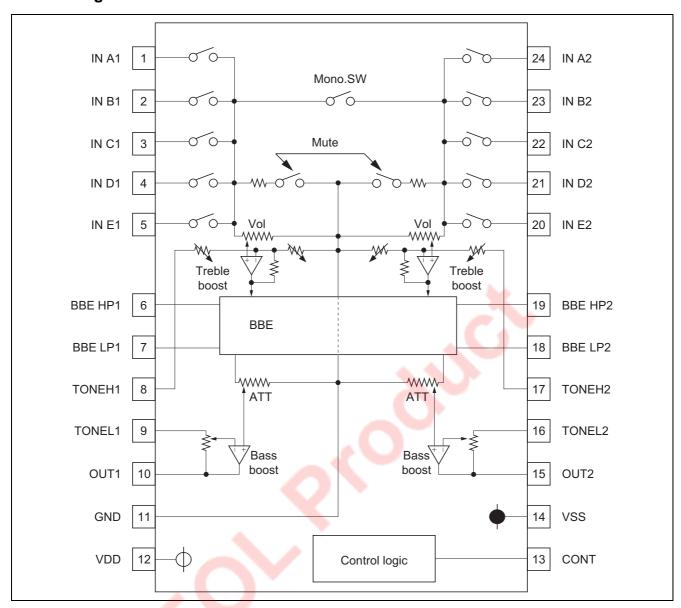
Recommended Operating Condition

Supply voltage range: ± 2.25 to ± 2.75 V

System Block Diagram



Block Diagram



Pin Description

Pin No.	Name	Function			
1	IN A1	INPUTs of the channel 1			
2	IN B1	The switch of INE can be controlled in dependently.			
3	IN C1	Please set "ALL OFF" mode when the switch of E is only ON.			
4	IN D1				
5	IN E1				
6	BBE HP1	BBE high pass filter 1			
7	BBE LP1	BBE low pass filter 1			
8	TONEH1	Treble control adjustment of the channel 1			
9	TONEL1	Bass control adjustment of the channel 1			
10	OUT1	OUTPUT of the channel 1			
11	GND	Ground			
12	VDD	Supply voltage (+)			
13	CONT	Control data input from a microcontroller			
14	VSS	Supply voltage (-)			
15	OUT2	OUTPUT of the channel 2			
16	TONEL2	Bass control adjustment of the channel 2			
17	TONEH2	Treble control adjustment of the channel 2			
18	BBE HP2	BBE high pass filter 2			
19	BBE LP2	BBE low pass filter 2			
20	IN E2	INPUTs of the channel 2			
21	IN D2	The switch of INE can be controlled independently.			
22	IN C2	Please set "ALL OFF" mode when the switch of E is only ON.			
23	IN B2				
24	IN A2				



Absolute Maximum Ratings

 $(Ta = 25^{\circ}C, unless otherwise noted)$

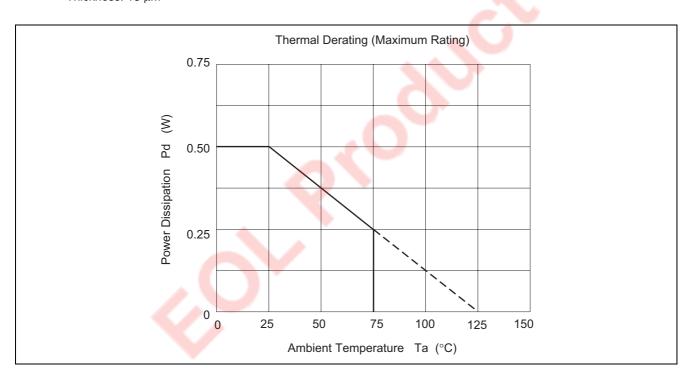
Item	Symbol	Ratings	Unit	Test Conditions
Supply voltage	VDD-VSS	6.0	V	
Thermal derating	Кθ	5	mW/°C	(Note)
Power dissipation	Pd	500	mW	
Operating temperature	Topr	-20 to 75	°C	
Storage temperature	Tstg	-40 to 125	°C	

Note: reference PC Board

Size: 70 mm × 70 mm Thickness: 1.6 mm Material: glass epoxy Copper pattern dimension

Width: 0.25 mm

Length: 25 to 30 mm/lead Thickness: 18 μm

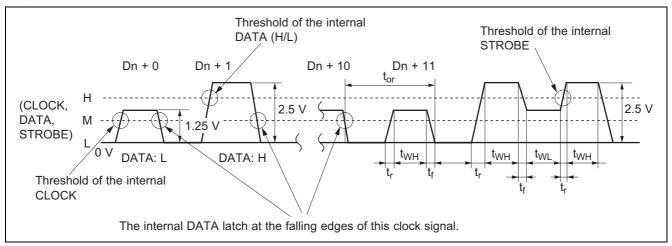


Recommended Operating Conditions

				Limits			
Item	Symbol	Pin No.	Min	Тур	Max	Unit	Condition
Supply voltage (+)	VDD	12	2.25	2.5	2.75	V	
Supply voltage (-)	VSS	14	-2.75	-2.5	-2.25		
Control data input voltage	CONT	13	GND	_	VDD		

Control Signals Specification

(1) Wave Form



(2) Voltage Control Signal

			Limits			
Digital	input signal	Min	Тур	Max	Unit	Condition
L signal	L	GND	_	0.4	V	VDD = 2.5 V, VSS = -2.5 V
M signal	М	1.0	1.25	1.5		VDD = 2.5 V, VSS = -2.5 V
			(VDD/2)			
H signal	Н	2.1	_	VDD	•	VDD = 2.5 V, VSS = -2.5 V

(3) Timing Control Signal

		Limits			
Item	Symbol	Min	Тур	Max	Unit
Cycle time of digital signal	t _{cr}	4	_		μS
Pulse width of digital signal ("H" level)	t _{WH}	1.6	_	_	
Pulse width of digital signal ("L" level)	t _{WLC}	1.6	_	_	
Rise time of digital signal	t _r	_	_	0.4	
Fall time of digital signal	t _f	_	_	0.4	

(4) Control Signal Example (Refer to the "Control Data Format")

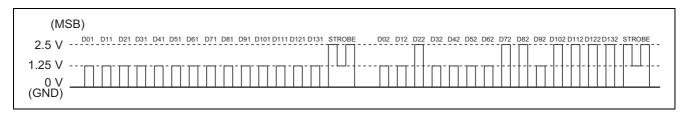
An example of the mode control

— VOL/TREBLE Share AMP Gain: 20 dB

Input: IN A,Volume: 0 dBMute: OFF

— BBE Effect: High level (+3 dB)

Mode: STEREOBass: 18 dBTreble: 6 dBRecout: ON (IN E)



Control Data Format

It is necessary to set up the all control data after power on.

(1) Input data(MSB) ← input order

Slot1

D01	D11	D21	D31	D41	D51	D61	D71	D81	D91	D101	D111	D121	D131
0	0	Vol/Tre	ble	Input		D2 to D	D2 to D6: (a) Master volume condition		Mute	CHIP/S	LOT		
		share a	ımp	0: IN A							ON/OFF	Select	
		gain S\	V	1: IN B							0: OFF	0: selec	t
		0: 20 d	В	2: IN C							1: ON	1: no se	elect
		1: 18 d	В	3: IN D							(Input	2: no se	elect
		2: 16 d	В								ALL	3: no se	elect
		3: 14 d	В								OFF)		

Slot2

D02	D12	D22	D32	D42	D52	D62	D72	D82	D92	D102	D112	D122	D132
0	0	BBE ef	fect	Mode s	elect	Bass (b	oost)		Treble	(boost)	IN E	CHIP/S	LOT
				0: stere	0: 0 dB, 1: 3 dB,		0: 0 dB,		ON/OFF	Select			
				1: mono1 only		2: 6 dB, 3: 9 dB,		1: 3 dB	,	0: OFF	0: no se	elect	
				2: mon	o2 only	4: 12 d	B, 5: 15 d	dB,	2: 6 dB	,	1: ON	1: no se	elect
				3: mon	o 1+2	6: 18 d	B, 7: 21 d	dB	3: 9 dB			2: no se	elect
										•		3: selec	ct

(a) Master volume

ATT	D61	D71	D81	D91	D101
-0.0 dB	0	0	0	0	0
-2.0 dB	1	0	0	0	0
-4.0 dB	0	1	0	0	0
-6.0 dB	1	1	0	0	0
-8.0 dB	0	0	1	0	0
-10.0 dB	1	0	1	0	0
-12.0 dB	0	1	1	0	0
-14.0 dB	1	1	1	0	0
-16.0 dB	0	0	0	1	0
-18.0 dB	1	0	0	1	0
-20.0 dB	0	1	0	1	0
-22.0 dB	1	1	0	1	0
-24.0 dB	0	0	1	1	0
-26.0 dB	1	0	1	1	0
−28.0 dB	0	1	1	1	0
−30.0 dB	1	1	1	1	0
−32.0 dB	0	0	0	0	1
−34.0 dB	1	0	0	0	1
−36.0 dB	0	1	0	0	1
-40.0 dB	1	1	0	0	1
-44.0 dB	0	0	1	0	1
-48.0 dB	1	0	1	0	1
−52.0 dB	0	1	1	0	1
−56.0 dB	1	1	1	0	1
-60.0 dB	0	0	0	1	1
−64.0 dB	1	0	0	1	1
-68.0 dB	0	1	0	1	1
−72.0 dB	1	1	0	1	1
-76.0 dB	0	0	1	1	1
-80.0 dB	1	0	1	1	1
-84.0 dB	0	1	1	1	1
the infinitesimal	1	1	1	1	1

(b) Input select

Input select		D41	D51	D111	D112
IN A	IN E off	0	0	0	0
IN B		1	0		
IN C		0	1		
IN D		1	1		
IN A to D all OFF	IN E on	*	*	1	1 (Note 1)
IN A-D select		A: 0	0	0	1 (Note 2)
		B: 1	0		
		C: 0	1		
		D: 1	1		

Notes: 1. The input impedance is about 5 k as input IN E.

2. IN E can be controlled independently. It can be used as Rec output.

(c) Mode control

Mode	D42	D52
stereo	0	0
mono 1 only	1	0
mono 2 only	0	1
mono1+2	1	1

(d) Treble control

Treble	D92	D102
0 dB	0	0
3 dB	1	0
6 dB	0	1
9 dB	1	1

(e) Bass control

Bass	D62	D72	D82
0 dB	0	0	0
3 dB	1	0	0
6 dB	0	1	0
9 dB	1	1	0
12 dB	0	0	1
15 dB	1	0	1
18 dB	0	1	1
21 dB	1	1	1

(f) Chip/Slot control

Chip/Slot	D12*	D13*
select (slot1)	0	0
no select	1	0
no select	0	1
select (slot1)	1	1

(g) Treble amp gain SW

Gain SW	D21	D31
20 dB	0	0
18 dB	1	0
16 dB	0	1
14 dB	1	1

(i) BBE effect

Effect	D22	D32
Bypass	0	0
BEE 1 high level +3dB	1	0
BEE 2 high level +7dB	0	1
BEE 3 high level +11dB	1	1

(2) Notice of Control Data

- 1. Input only the control data at (1) Input Data.
- 2. It is necessary to set up the all control data after power-on, although the internal circuit forced as belows, when $(VDD-VSS) \le 3.3 \text{ V (Typ)}$.
- 3 The interval of data transmission from the microcontroller is over 0.1s. This is waiting time for soft-switching to reduce the shocknoise.

Item	Condition
Gain SW	18 dB
Input select	ALL OFF
Master volume	the infinitesimal
MUTE	ON (Input ALL OFF)
BBE effect	Bypass
Mode select	Stereo
Bass	0 dB
Treble	0 dB
IN E	ON

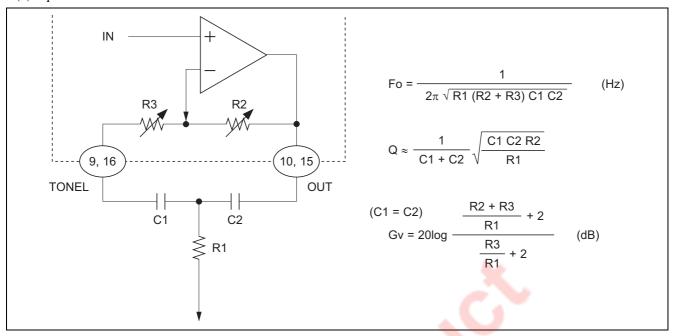
Electrical Characteristics

 $(VDD=2.5\ V,\ VSS=-2.5\ V,\ f=1\ kHz,\ Vi=100\ mV(rms),\ Vol=0\ dB,\ Bass=0\ dB,\ Treble=0\ dB,\ Vol/Treble$ Share AMP = 18 dB, Surround = Bypass, RL = 10 k Ω , Ta = 25°C, unless otherwise noted)

		Limits						
Item	Symbol	Min	Тур	Max	Unit	Conditions		
Circuit current of positive power supply	IDD	1	30	45	mA	Quiescent		
Circuit current of negative power supply	ISS		-30	-45	mA	Quiescent		
Voltage gain (selector)	Gv1	16	18	20	dB	Vol/Treble share amp gain = 18 dB Bypass		
Voltage gain (tone control)	Gv2	25.5	27.5	29.5	dB	Vol/Treble share amp gain = 18 dB Q surround mode Vi = 20mVrms		
Maximum output voltage	Vomax	1.2	1.6		Vrms	RL = 10 k, THD = 1%		
Total harmonic distortion	THD	_	0.02	0.08	%	BW = 400 to 30 kHz		
Output noise voltage	No1	_	8	20	μVrms	JIS-A, Rg = 5.1 k, VOL = the infinitesimal BYPASS		
	No2	-	15	40	μVrms	JIS-A, Rg = 5.1 k, VOL = the infinitesimal BBE3 (High level +11 dB) mode		
Maximum attenuation	ATTmax		-95	-90	dB	Output referencelevel (Vo = 1 Vrms), ATT = the infinitesimal, JIS-A		
Bass boost	GB1	1.5	3	4.5	dB	3 dB $f = 1 \text{ kHz}, Vo = 80 \text{ mVrms}$		
	GB2	4.5	6	7.5		6 dB		
	GB3	7.5	9	10.5		9 dB		
	GB4	10.5	12	13.5	"	12 dB		
	GB5	13.5	15	16.5		15 dB		
	GB6	16.5	18	19.5		18 dB		
	GB7	19.5	21	22.5		21 dB		
Treble boost	GT1	1.5	3	4.5		3 dB $f = 1 \text{ kHz}, Vo = 80 \text{ mVrms}$		
	GT2	4.5	6	7.5		6 dB		
	GT3	7.5	9	10.5		9 dB		
Low level boost (f = 20Hz)	BBE1		3	_	dB	f = 20 Hz, Vo = 80 mVrms		
High level boost (f = 10kHz)	BBE2	J	11	_		f = 10 kHz, Vo = 80 mVrms		

Function Description

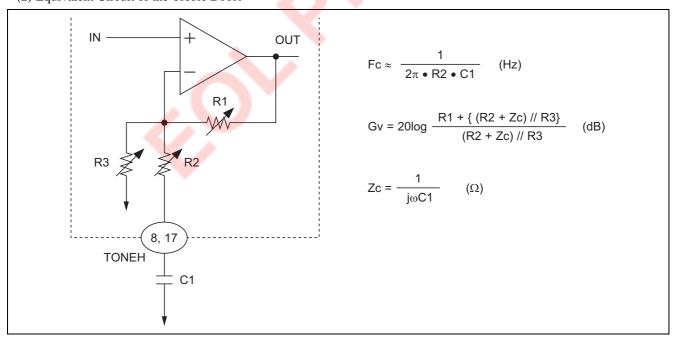
(1) Equivalent Circuit of the Bass Boost



R2, R3 (typical)

Bass boo	ost	3 dB	6 dB	9 dB	12 dB	15 dB	18 dB	21 dB
Resistor (k)	R2	15.4	25.7	32.9	38.7	41.6	44.2	46
	R3	30.6	20.3	13.1	7.3	4.4	1.8	0

(2) Equivalent Circuit of the Treble Boost



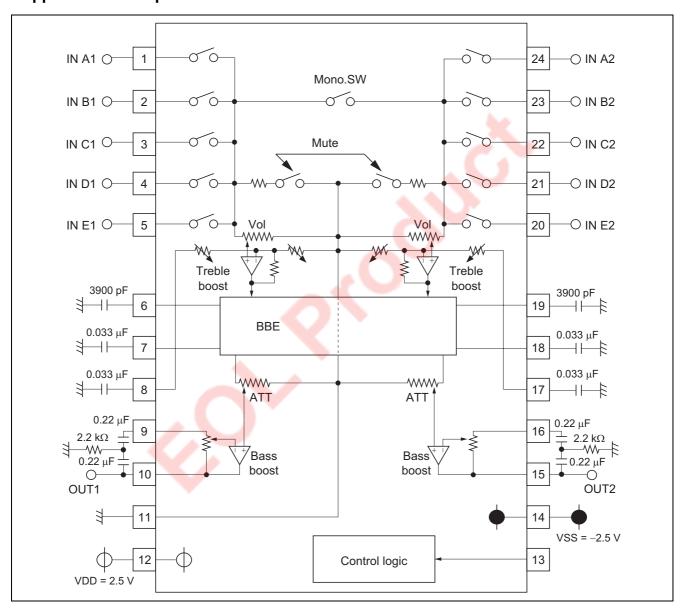
R2 (typical)

Treble boost	3 dB	6 dB	9 dB
R2 (k)	5.3	2.2	1.2

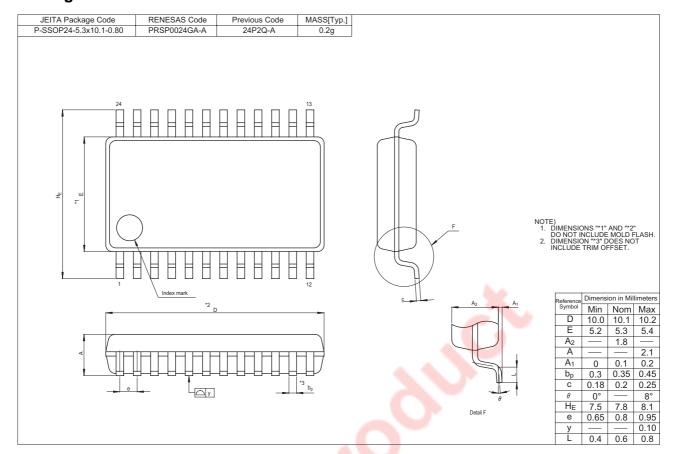
R1, R3 (typical)

Gain	14 dB	16 dB	18 dB	20 dB
R1 (k)	10.88	13.65	17.21	21.60
R3 (k)	2.72	2.57	2.48	2.40

Application Example



Package Dimensions



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